TOSHIBA Field Effect Transistor Silicon N Channel MOS Type ( $\pi$ -MOS V)

# 2SK3176

# Switching Regulator, DC-DC Converter and Motor Drive Applications

Low drain-source ON resistance: R<sub>DS</sub> (ON) = 38 mΩ (typ.)

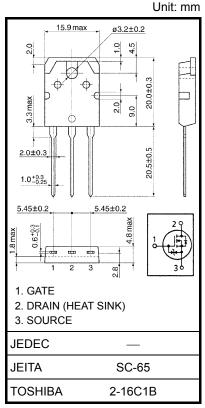
High forward transfer admittance: |Y<sub>fs</sub>| = 30 S (typ.)

Low leakage current: I<sub>DSS</sub> = 100 mA (max) (V<sub>DS</sub> = 200 V)

• Enhancement-mode:  $V_{th}$  = 1.5 to 3.5 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	200	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	200	V	
Gate-source voltage		$V_{GSS}$	±20	٧	
Drain current	DC (Note 1)	ΙD	30	^	
	Pulse (Note 1)	$I_{DP}$	120	А	
Drain power dissipation (Tc = 25°C)		$P_{D}$	150	W	
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	925	mJ	
Avalanche current		I <sub>AR</sub>	30	Α	
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	15	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 4.6 g (typ.)

Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2:  $V_{DD} = 50$  V,  $T_{ch} = 25$ °C (initial), L = 1.66 mH,  $R_G = 25$   $\Omega$ ,  $I_{AR} = 30$  A

Note 3: Repetitive rating: pulse width limited by maximum junction temperature.

Note 4: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic sensitive device.

Please handle with caution.

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	0.833	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50.0	°C/W

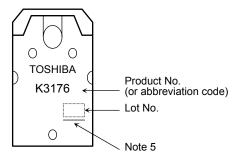
### **Electrical Characteristics (Ta = 25°C)**

Characteri	istics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 200 V, V <sub>GS</sub> = 0 V		_	100	μА
Drain-source breakdo	wn voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	200	_		٧
Gate threshold voltage	Э	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	_	3.5	٧
Drain-source ON resis	stance	R <sub>DS (ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A		38	52	mΩ
Forward transfer admi	ittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 15 A	15	30		S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	5400	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		580		pF
Output capacitance		Coss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	1900	_	pF
Switching time	Rise time	t <sub>r</sub>	VGS 0 V	_	15	_	
	Turn-on time	t <sub>on</sub>		_	55		- ns
	Fall time	t <sub>f</sub>		_	25		
	Turn-off time	t <sub>off</sub>	$V_{DD} \simeq 100 \text{ V}$ Duty $\leq$ 1%, $t_W = 10 \mu\text{s}$		190		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq$ 160 V, $V_{GS} =$ 10 V, $I_D =$ 30 A	_	125	_	nC
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \simeq 160 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	_	80	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>	$V_{DD} \simeq 160 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	_	45		nC

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	30	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	90	Α
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-2.0	٧
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V},$ $dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$	_	270		ns
Reverse recovery charge	Q <sub>rr</sub>	$I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V},$ $dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$	_	3.0		μС

## Marking

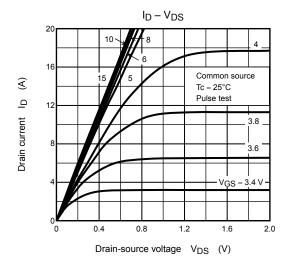


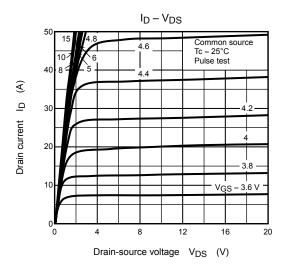
Note 5: A line under a Lot No. identifies the indication of product Labels.

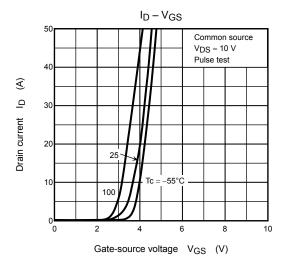
Not underlined: [[Pb]]/INCLUDES > MCV

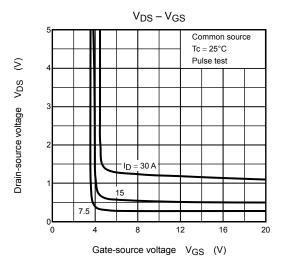
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

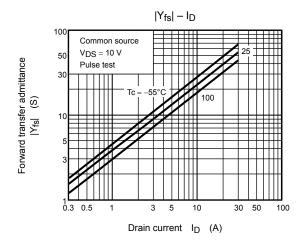
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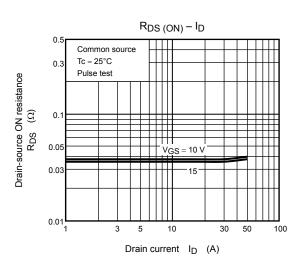




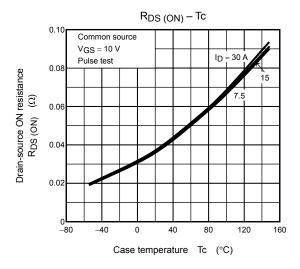


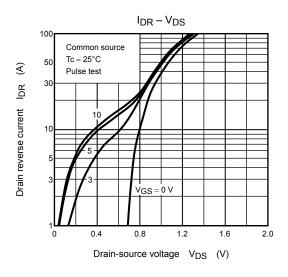


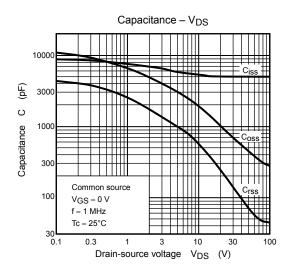


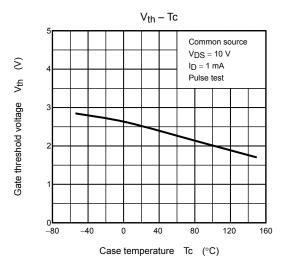


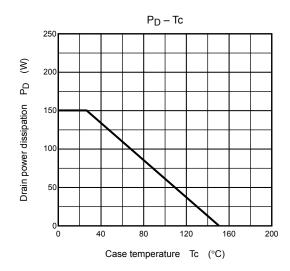
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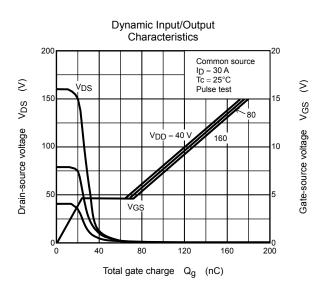


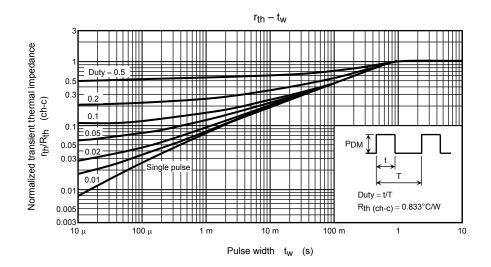


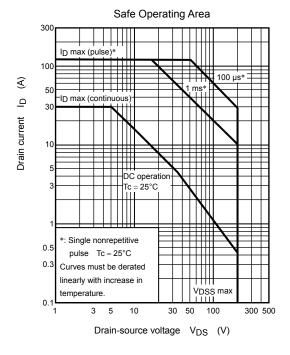


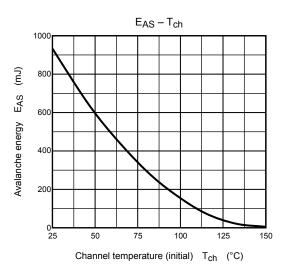


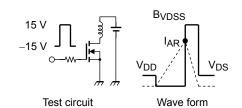












$$R_G = 25 \Omega$$
  
 $V_{DD} = 50 \text{ V, L} = 1.66 \text{ mH}$ 

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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